NSN 5961-01-545-8609

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Inclosure Material:

Metal

Overall Height:

Between 0.670 inches and 0.710 inches

Overall Diameter:

Between 0.209 inches and 0.230 inches

End Application:

Circuit card assembly

Features Provided:

Electrostatic sensitive

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

60.0 collector to emitter voltage, dc

Current Rating Per Characteristic:

50.00 milliamperes all primaries

Power Rating Per Characteristic:

1.2 milliwatts small-signal input power, common-collector absolute

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Product Name:

(inavy)semiconductor devic (drawing)semiconductor device, transistor, amplifier, pnp, silicon(a3263509)

Special Features:

Operating temperature: -65 to 200 degrees celsius

Terminal Type And Quantity:

4 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

A110a0